

**STPS160A/U**

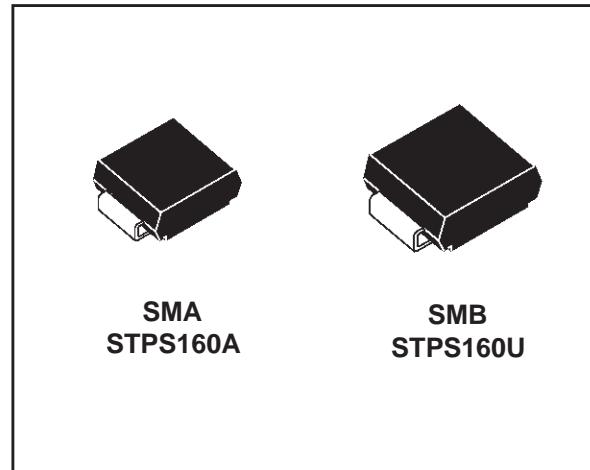
## POWER SCHOTTKY RECTIFIER

### MAIN PRODUCT CHARACTERISTICS

I <sub>F(AV)</sub>	1 A
V <sub>RRM</sub>	60 V
V <sub>F</sub> (max)	0.57 V

### FEATURES AND BENEFITS

- VERY SMALL CONDUCTION LOSSES
- NEGLIGIBLE SWITCHING LOSSES
- LOW FORWARD VOLTAGE DROP
- SURFACE MOUNTED DEVICE



### DESCRIPTION

Single chip Schottky rectifier suited for Switch-mode Power Supplies and high frequency DC to DC converters.

Packaged in SMA or SMB(\*), this device is intended for surface mounting and used in low voltage, high frequency inverters, free wheeling and polarity protection applications.

(\*) in accordance with JEDEC DO214AC and DO214AA standard

### ABSOLUTE RATINGS (limiting values)

Symbol	Parameter		Value	Unit
V <sub>RRM</sub>	Repetitive peak reverse voltage		60	V
I <sub>F(RMS)</sub>	RMS forward current		10	A
I <sub>F(AV)</sub>	Average forward current	T <sub>Lead</sub> = 130°C δ = 0.5	1	A
I <sub>FSM</sub>	Surge non repetitive forward current	tp = 10 ms Sinusoidal	75	A
I <sub>RRM</sub>	Repetitive peak reverse current	tp = 2 μs F = 1kHz	1	A
I <sub>RSR</sub>	Non repetitive peak reverse current	tp = 100μs square	1	A
T <sub>stg</sub>	Storage temperature range		- 65 to + 150	°C
T <sub>j</sub>	Maximum junction temperature		150	
dV/dt	Critical rate of rise of reverse voltage		10000	V/μs

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### THERMAL RESISTANCES

Symbol	Parameter		Value	Unit
R <sub>th</sub> (j-l)	Junction to lead	SMA	30	°C/W
		SMB	23	

### STATIC ELECTRICAL CHARACTERISTICS

Symbol	Tests Conditions	Tests Conditions		Min.	Typ.	Max.	Unit
I <sub>R</sub> *	Reverse leakage current	T <sub>j</sub> = 25°C	V <sub>R</sub> = 60V			4	μA
		T <sub>j</sub> = 125°C			1.1	4	mA
V <sub>F</sub> **	Forward voltage drop	T <sub>j</sub> = 25°C	I <sub>F</sub> = 1 A			0.67	V
		T <sub>j</sub> = 125°C	I <sub>F</sub> = 1 A		0.49	0.57	
		T <sub>j</sub> = 25°C	I <sub>F</sub> = 2 A			0.8	
		T <sub>j</sub> = 125°C	I <sub>F</sub> = 2 A		0.58	0.65	

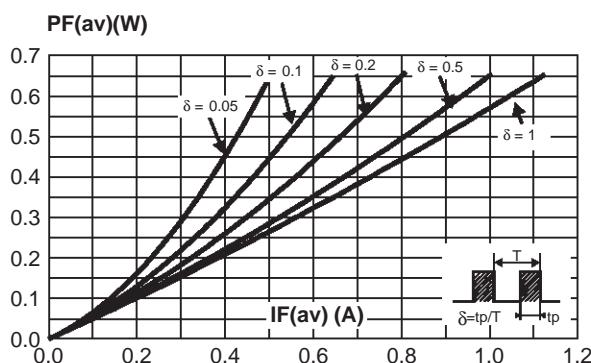
Pulse test : \* tp = 5 ms, δ < 2 %

\*\* tp = 380 μs, δ < 2%

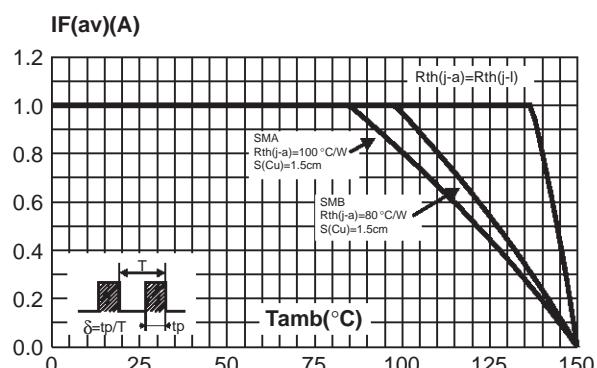
To evaluate the maximum conduction losses use the following equation :

$$P = 0.49 \times I_{F(AV)} + 0.08 \times I_{F}^2(RMS)$$

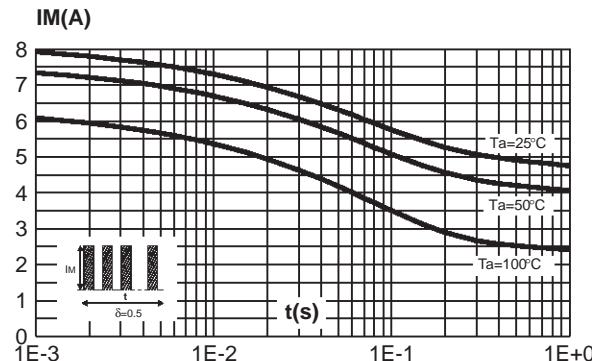
**Fig. 1:** Average forward power dissipation versus average forward current.



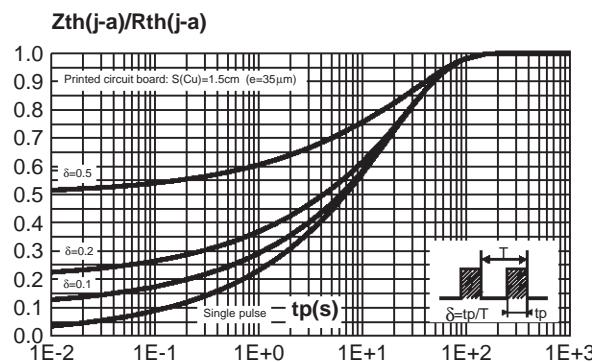
**Fig. 2:** Average forward current versus ambient temperature (δ=0.5).



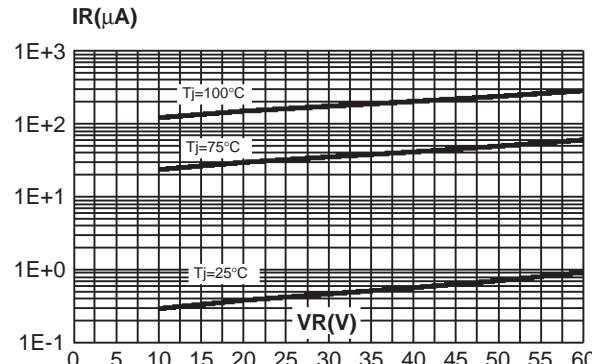
**Fig. 3-1:** Non repetitive surge peak forward current versus overload duration (maximum values) (SMB).



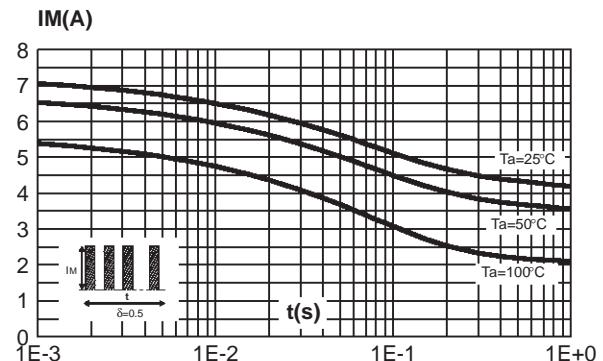
**Fig. 4-1:** Relative variation of thermal impedance junction to ambient versus pulse duration (SMB).



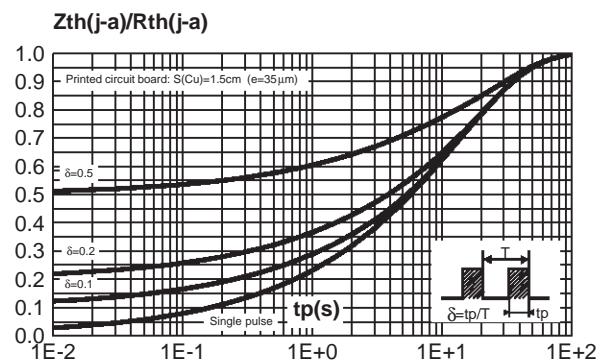
**Fig. 5:** Reverse leakage current versus reverse voltage applied (typical values).



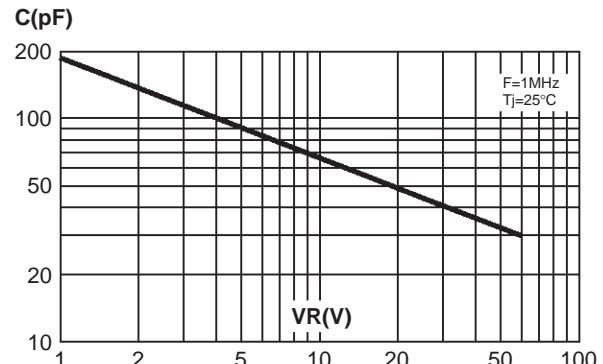
**Fig. 3-2:** Non repetitive surge peak forward current versus overload duration (maximum values) (SMA).



**Fig. 4-2:** Relative variation of thermal impedance junction to ambient versus pulse duration (SMA).

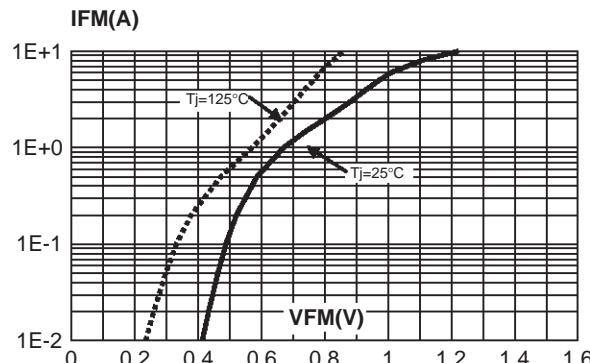


**Fig. 6:** Junction capacitance versus reverse voltage applied (typical values).

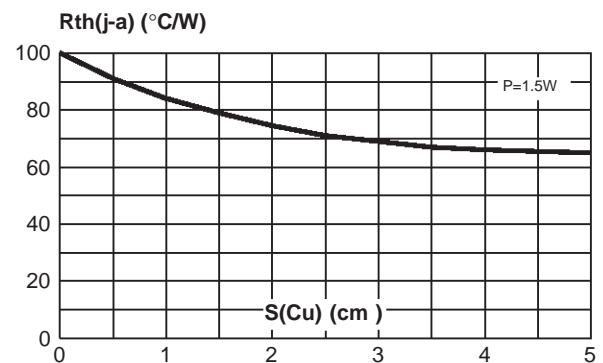


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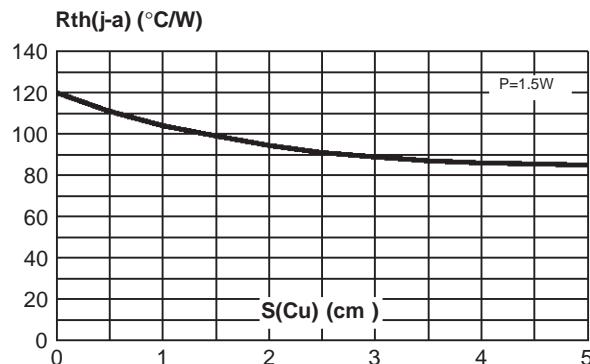
**Fig. 7:** Forward voltage drop versus forward current (maximum values).



**Fig. 8-1:** Thermal resistance junction to ambient versus copper surface under each lead (Epoxy printed circuit board, copper thickness: 35 $\mu m$ )(SMB).



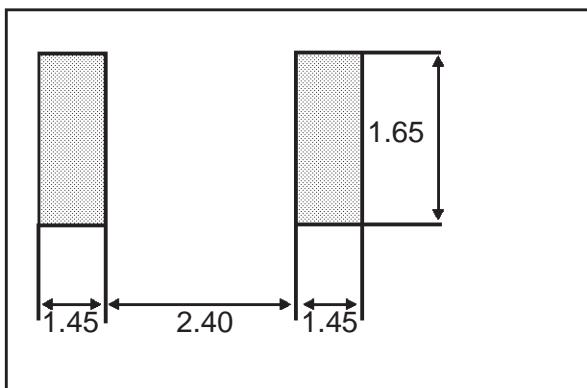
**Fig. 8-2:** Thermal resistance junction to ambient versus copper surface under each lead (Epoxy printed circuit board, copper thickness: 35 $\mu m$ )(SMA).



**PACKAGE MECHANICAL DATA**  
SMA

REF.	DIMENSIONS			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A1	1.90	2.70	0.075	0.106
A2	0.05	0.20	0.002	0.008
b	1.25	1.65	0.049	0.065
c	0.15	0.41	0.006	0.016
E	4.80	5.60	0.189	0.220
E1	3.95	4.60	0.156	0.181
D	2.25	2.95	0.089	0.116
L	0.75	1.60	0.030	0.063

**FOOT PRINT DIMENSIONS ( in millimeters)**



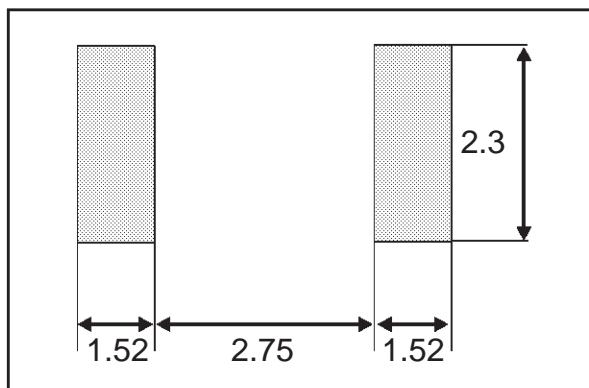
■ **Marking:** S160

## STPS160A/U

### PACKAGE MECHANICAL DATA SMB

REF.	DIMENSIONS			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A1	1.90	2.45	0.075	0.096
A2	0.05	0.20	0.002	0.008
b	1.95	2.20	0.077	0.087
c	0.15	0.41	0.006	0.016
E	5.10	5.60	0.201	0.220
E1	4.05	4.60	0.159	0.181
D	3.30	3.95	0.130	0.156
L	0.75	1.60	0.030	0.063

### FOOT PRINT DIMENSIONS ( in millimeters)



■ **Marking:** E16  
Cathode band indicated cathode

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